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PATENT *Mollish*

Atty. Docket No. 0630-1290P

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Myoung Goo LEE et al. Conf.: 4397
Appl. No.: 10/028,432 Group: 2815
Filed: December 28, 2001 Examiner: LANDAU, M.C.
For: MULTI-FINGER TYPE ELECTROSTATIC DISCHARGE
PROTECTION CIRCUIT

AMENDMENT

Assistant Commissioner for Patents
Washington, DC 20231

October 2, 2002

Sir:

The following amendments and remarks are submitted under 37 C.F.R. § 1.111 in response to the Office Action dated July 3, 2002 in connection with the above-identified application.

In the Specification

Please amend the specification as follows:

Paragraph [27] has been amended as follows:

A1 [27] For each active region 200, the drain regions 202 and 205 are connected to an input or output pad, the source region 206 is connected to a ground Vss, and the pair of the gates 203 and 204 are connected to the ground Vss or an output of a pull-down inverter when used as a pull-down transistor. The n+ active region 201 between two active regions 200 is connected to Vcc reference voltage (or ground Vss when the active region 201 is of p+ type).

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